

## **Description**

The HXY30P02D uses advanced trench technology to provide excellent  $R_{DS(ON)}$ , low gate charge and operation with gate voltages as low as 4.5V. This device is suitable for use as a Battery protection or in other Switching application.



TO-252-2L

### **General Features**

 $V_{DS} = -18V I_{D} = -25 A$ 

 $R_{DS(ON)}$  < 25 m $\Omega$  @  $V_{GS}$ =-4.5 V

# G S

# **Application**

Battery protection

Load switch

Uninterruptible power supply

P-Channel MOSFET

**Package Marking and Ordering Information** 

Product ID	Pack	Marking	Qty(PCS)
HXY30P02D	TO252-2L	30P02 XXX YYY	2500

Absolute Maximum Ratings (T<sub>C</sub>=25 ℃ unless otherwise noted)

		Rating		
Symbol	Parameter	Steady State	Units	
Vos	Drain-Source Voltage	-18	V	
Vgs	Gate-Source Voltage	±12	V	
I <sub>D</sub> @T <sub>C</sub> =25°C	Continuous Drain Current, V <sub>GS</sub> @ -10V <sup>1</sup>	-25	Α	
I <sub>D</sub> @T <sub>C</sub> =75 °C	Continuous Drain Current, V <sub>GS</sub> @ -10V <sup>1</sup>	-15	А	
Ірм	Pulsed Drain Current <sup>2</sup>	-38	А	
P <sub>D</sub> @T <sub>C</sub> =25°C	Total Power Dissipation⁴	3.9	W	
Тѕтс	Storage Temperature Range	-55 to 150	°C	
TJ	Operating Junction Temperature Range	-55 to 150	°C	
R <sub>0</sub> JA	Thermal Resistance Junction-Ambient <sup>1</sup>	45	°C/W	
Rejc	Thermal Resistance Junction-Case <sup>1</sup>	50	°C/W	



# **Electrical Characteristics** (T<sub>J</sub>=25°C unless otherwise specified)

Symbol	Parameter	Test Condition	Min.	Тур.	Max.	Units	
Off Charac	Off Characteristic						
V <sub>(BR)DSS</sub>	Drain-Source Breakdown Voltage	V <sub>GS</sub> =0V, I <sub>D</sub> = -250μA	-15	-18	_	V	
I <sub>DSS</sub>	Zero Gate Voltage Drain Current	V <sub>DS</sub> = -12V, V <sub>GS</sub> =0V,	-	-	-1	μA	
I <sub>GSS</sub>	Gate to Body Leakage Current	$V_{DS}$ =0V, $V_{GS}$ = ±12V	-	-	±100	nA	
On Charac	On Characteristics						
V <sub>GS(th)</sub>	Gate Threshold Voltage	V <sub>DS</sub> =V <sub>GS</sub> , I <sub>D</sub> = -250μA	-0.4	-0.7	-1.0	V	
0	Static Drain-Source on-Resistance	V <sub>GS</sub> = -4.5V, I <sub>D</sub> = -7A	-	17	25	m 0	
$R_{DS(on)}$		V <sub>GS</sub> = -2.5V, I <sub>D</sub> = -5A	-	22	30	mΩ	
Dynamic (	Characteristics						
C <sub>iss</sub>	Input Capacitance	\\ - 0\\ \\ - 0\\	-	1300	-	рF	
Coss	Output Capacitance	$V_{DS} = -6V, V_{GS} = 0V,$	-	302	-	pF	
C <sub>rss</sub>	Reverse Transfer Capacitance	f=1.0MHz	-	279	-	pF	
Qg	Total Gate Charge	- V <sub>DS</sub> = -6V, I <sub>D</sub> = -7A, - V <sub>GS</sub> = -4.5V	-	19	-	nC	
Q <sub>gs</sub>	Gate-Source Charge		-	4	-	nC	
$Q_{gd}$	Gate-Drain("Miller") Charge	7 VGS4.5V	-	5	-	nC	
Switching	Characteristics						
t <sub>d(on)</sub>	Turn-on Delay Time	)/ O)/ I AA	-	11	-	ns	
t <sub>r</sub>	Turn-on Rise Time	$V_{DD} = -6V, I_D = -4A,$	-	36	-	ns	
t <sub>d(off)</sub>	Turn-off Delay Time	$V_{GS} = -4.5V$ ,	-	29	-	ns	
t <sub>f</sub>	Turn-off Fall Time	$R_{\text{GEN}}=2.5\Omega$	-	8	-	ns	
Drain-Sou	rce Diode Characteristics and Maxim	num Ratings					
Is	Maximum Continuous Drain to Source Diode Forw		_	_	-25	Α	
- 0	Current			_	20	/\	
I <sub>SM</sub>	Maximum Pulsed Drain to Source Diode Forward Current		-	-	-38	Α	
$V_{\text{SD}}$	Drain to Source Diode Forward Voltage	V <sub>GS</sub> =0V, I <sub>S</sub> = -7A	-	-0.8	-1.2	٧	

Notes:1. Repetitive Rating: Pulse Width Limited by Maximum Junction Temperature

<sup>2.</sup> Pulse Test: Pulse Width≤300µs, Duty Cycle≤2%



# **Typical Performance Characteristics**

Figure1: Output Characteristics

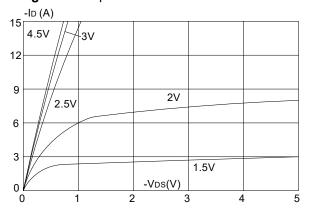


Figure 3:On-resistance vs. Drain Current

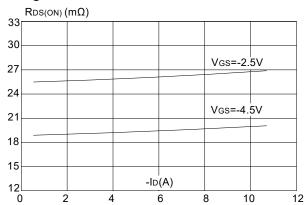


Figure 5: Gate Charge Characteristics

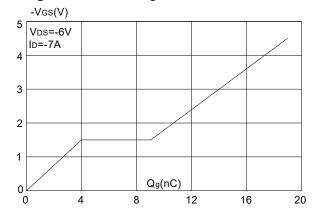


Figure 2: Typical Transfer Characteristics

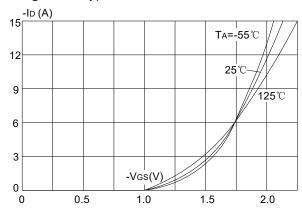


Figure 4: Body Diode Characteristics

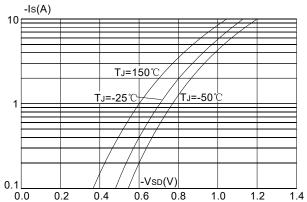
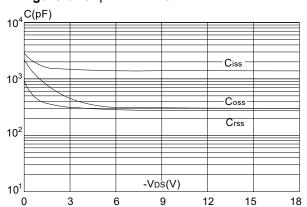


Figure 6: Capacitance Characteristics





**Figure 7:** Normalized Breakdown Voltage vs. Junction Temperature

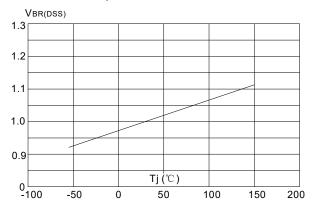
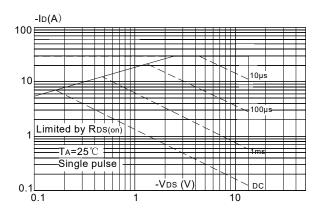
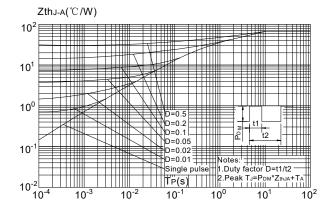


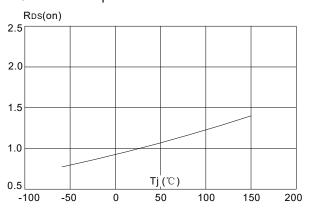
Figure 9: Maximum Safe Operating Area



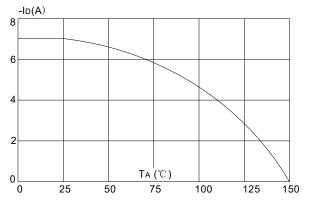
**Figure.11:** Maximum Effective Transient Thermal Impedance, Junction-to-Ambient



**Figure 8:** Normalized on Resistance vs. Junction Temperature

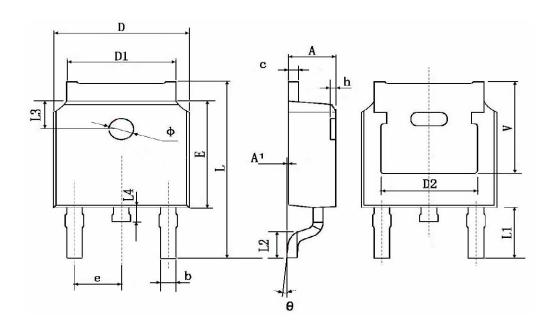


**Figure 10:** Maximum Continuous Drain Current vs. Ambient Temperature





# **TO252-2L Package Information**



Symbol	Dimensions In Millimeters		Dimensions In Inches			
	Min.	Max.	Min.	Max.		
A	2.200	2.400	0.087	0.094		
A1	0.000	0.127	0.000	0.005		
b	0.660	0.860	0.026	0.034		
С	0.460	0.580	0.018	0.023		
D	6.500	6.700	0.256	0.264		
D1	5.100	5.460	0.201	0.215		
D2	4.830	4.830 TYP.		0.190 TYP.		
Е	6.000	6.200	0.236	0.244		
е	2.186	2.386	0.086	0.094		
L	9.800	10.400	0.386	0.409		
L1	2.900	TYP.	0.114 TYP.			
L2	1.400	1.700	0.055	0.067		
L3	1.600	1.600 TYP.		0.063 TYP.		
L4	0.600	1.000	0.024	0.039		
Ф	1.100	1.300	0.043	0.051		
θ	0°	8°	0°	8°		
h	0.000	0.300	0.000	0.012		
V	5.350	TYP.	0.211 TYP.			

## **Attention**

- Any and all HUA XUAN YANG ELECTRONICS products described or contained herein do not have specifications that can handle applications that require extremely high levels of reliability, such as life-support systems, aircraft's control systems, or other applications whose failure can be reasonably expected to result in serious physical and/or material damage. Consult with your HUA XUAN YANG ELECTRONICS representative nearest you before using any HUA XUAN YANG ELECTRONICS products described or contained herein in such applications.
- HUA XUAN YANG ELECTRONICS assumes no responsibility for equipment failures that result from using products at values that exceed, even momentarily, rated values (such as maximum ratings, operating condition ranges, or other parameters) listed in products specifications of any and all HUA XUAN YANG ELECTRONICS products described or contained herein.
- Specifications of any and all HUA XUAN YANG ELECTRONICS products described or contained herein stipulate the performance, characteristics, and functions of the described products in the independent state, and are not guarantees of the performance, characteristics, and functions of the described products as mounted in the customer's products or equipment. To verify symptoms and states that cannot be evaluated in an independent device, the customer should always evaluate and test devices mounted in the customer's products or equipment.
- HUA XUAN YANG ELECTRONICS CO.,LTD. strives to supply high-quality high-reliability products. However, any and all semiconductor products fail with some probability. It is possible that these probabilistic failures could give rise to accidents or events that could endanger human lives, that could give rise to smoke or fire, or that could cause damage to other property. When designing equipment, adopt safety measures so that these kinds of accidents or events cannot occur. Such measures include but are not limited to protective circuits and error prevention circuits for safe design, redundant design, and structural design.
- In the event that any or all HUA XUAN YANG ELECTRONICS products(including technical data, services) described or contained herein are controlled under any of applicable local export control laws and regulations, such products must not be exported without obtaining the export license from the authorities concerned in accordance with the above law.
- No part of this publication may be reproduced or transmitted in any form or by any means, electronic or mechanical, including photocopying and recording, or any information storage or retrieval system, or otherwise, without the prior written permission of HUA XUAN YANG ELECTRONICS CO.,LTD.
- Information (including circuit diagrams and circuit parameters) herein is for example only; it is not guaranteed for volume production.

  HUA XUAN YANG ELECTRONICS believes information herein is accurate and reliable, but no guarantees are made or implied regarding its use or any infringements of intellectual property rights or other rights of third parties.
- Any and all information described or contained herein are subject to change without notice due to product/technology improvement, etc. When designing equipment, refer to the "Delivery Specification" for the HUA XUAN YANG ELECTRONICS product that you intend to use.